

## isc Silicon PNP Power Transistor

# 2SA1358

#### **DESCRIPTION**

- High Collector-Emitter Breakdown Voltage
  - : V<sub>(BR)CEO</sub>= -120V(Min)
- · Complement to Type 2SC3421
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

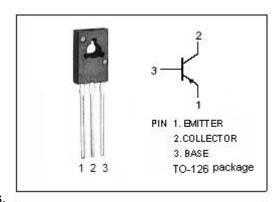
## **APPLICATIONS**

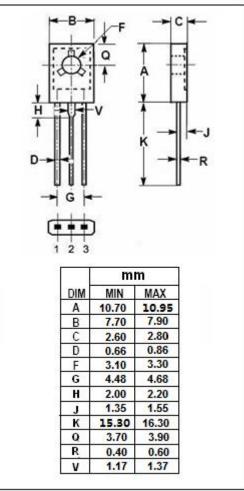


• Designed for audio frequency power amplifier applications.

# ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	-120	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-120	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V	
Ic	Collector Current-Continuous	-1	А	
I <sub>B</sub>	Base Current-Continuous	ous -0.1 A		
Pc	Collector Power Dissipation @ $T_c$ =25 $^{\circ}$ C	10	W	
	Collector Power Dissipation @ T <sub>a</sub> =25 °C	1.5		
TJ	Junction Temperature	150	$^{\circ}$ C	
T <sub>stg</sub>	Storage Temperature Range -55~150		$^{\circ}$ C	







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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -10mA ; I <sub>B</sub> = 0	-120			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -1mA ; I <sub>C</sub> = 0	-5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage I <sub>C</sub> = -500mA; I <sub>B</sub> = -50mA				-1.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -500mA ; V <sub>CE</sub> = -5V			-1.0	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -120V; I <sub>E</sub> = 0			-0.1	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-0.1	μ <b>А</b>
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = -0.1A; V <sub>CE</sub> = -5V	80		240	
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> = -0.1A; V <sub>CE</sub> = -5V		120		MHz
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = -10V, f <sub>test</sub> = 1MHz		30		pF

### h<sub>FE</sub> Classifications

0	Y
80-160	120-240

### Notice:

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